

Dimensions in mm

Features

- Double differential magneto resistor on one carrier
- Accurate intercenter spacing
- High operating temperature range
- High output voltage
- Compact construction
- Available in strip form for automatic assembly
- Optimized intercenter spacing on modules
 $m = 0.5 \text{ mm}$
- Reduced temperature dependence of offset voltage

Typical applications

- Incremental angular encoders
- Detection of sense of rotation
- Detection of speed
- Detection of position

Type	Ordering Code
FP 425 L 90	Q65425-L90 (singular)
FP 425 L 90	Q65425-L0090E001 (taped)

The double differential magneto resistor assembly consists of two pairs of magneto resistors, (L-type InSb/NiSb semiconductor resistors whose resistance value can be magnetically controlled), which are fixed to a silicon substrate. Contact to the magneto resistors is achieved using a copper/polyimide carrier film known as TAB.

The basic resistance of each of the magneto resistors is 90 Ω . The two series coupled pairs of magneto resistor are actuated by an external magnetic field or can be biased by a permanent magnet and actuated by a soft iron target.

Maximum ratings

Parameter	Symbol	Value	Unit
Operating temperature	T_A	- 40 / + 175	°C
Storage temperature	T_{stg}	- 40 / + 185	°C
Power dissipation ¹⁾	P_{tot}	800	mW
Supply voltage ($B = 0.2$ T, $T_A = 25$ °C)	V_{IN}	8	V
Thermal conductivity – attached to heatsink – in still air	G_{thcase} G_{thA}	20 2	mW/K mW/K

Characteristics ($T_A = 25$ °C)

Nominal supply voltage ($B = 0.2$ T) ²⁾	V_{INN}	5	V
Basic resistance ($I < 1$ mA, $B = 0$ T)	R_{01-3}	160 – 280	Ω
Center symmetry ³⁾	M	≤ 3	%
Relative resistance change ($R_0 = R_{01-3}$, R_{04-6} at $B = 0$ T) $B = \pm 0.3$ T ⁴⁾ $B = \pm 1$ T	R_B/R_0	> 1.7 > 7	–
Temperature coefficient $B = 0$ T $B = \pm 0.3$ T $B = \pm 1$ T	TC_R	- 0.16 - 0.38 - 0.54	%/K %/K %/K

1) $T = T_{case}$

2) $T = T_{case}$, $T < 80$ °C

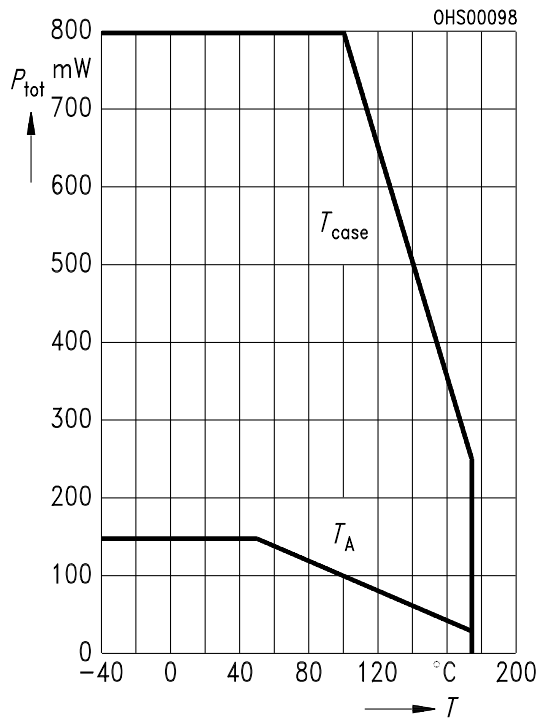
3)
$$M = \frac{R_{01-2} - R_{02-3}}{R_{01-2}} \times 100\% \text{ for } R_{01-2} > R_{02-3}$$

$$M = \frac{R_{04-5} - R_{05-6}}{R_{04-5}} \times 100\% \text{ for } R_{04-5} > R_{05-6}$$

4) 1 T = 1 Tesla = 10^4 Gauss

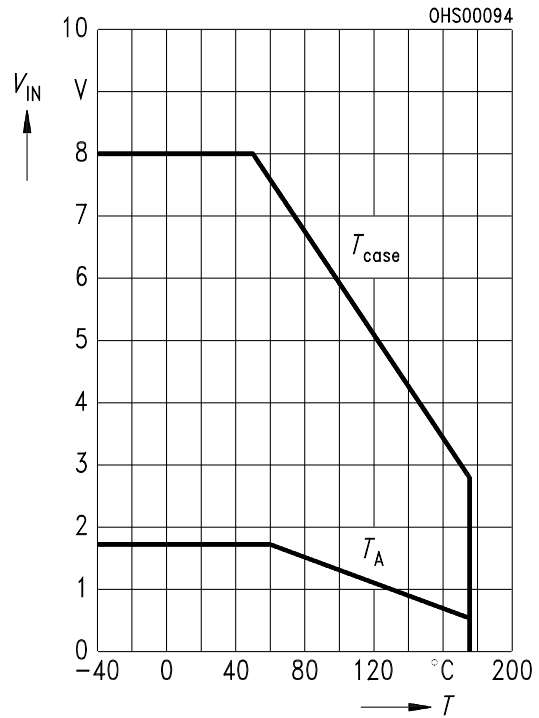
Max. power dissipation versus temperature

$P_{tot} = f(T), T = T_{case}, T_A$



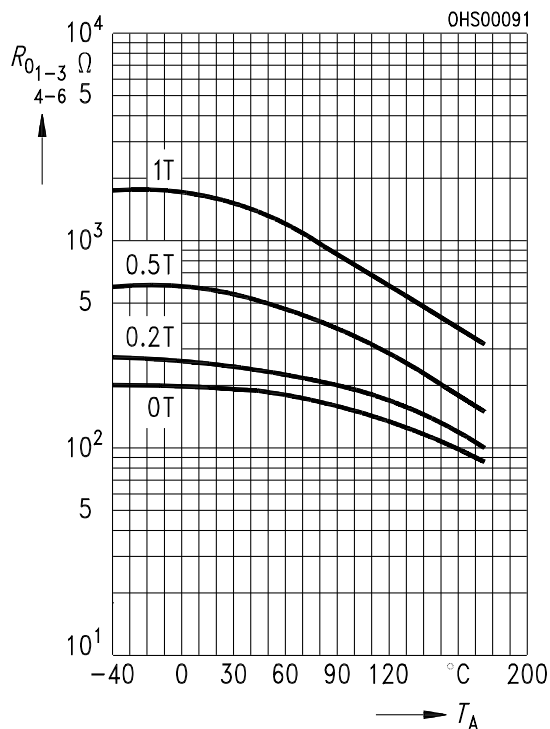
Maximum supply voltage versus temperature

$V_{IN} = f(T), B = 0.2 T$



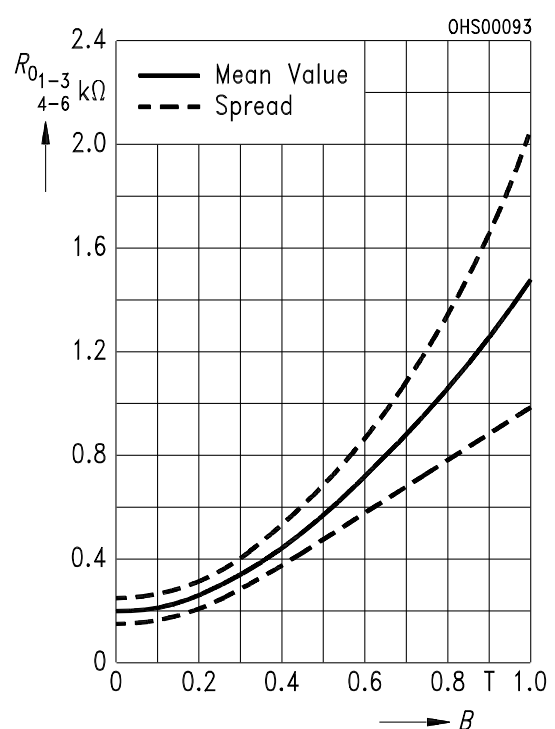
Typical MR resistance versus temperature

$R_{01-3, 4-6} = f(T_A), B = \text{Parameter}$



Typical MR resistance versus magnetic induction B

$R_{01-3, 4-6} = f(B), T_A = 25 °C$





LittleDiode supplies new, hard to find or obsolete electronic components and semiconductors all over the world.

With over two million different components listed you are sure to find the part you need.

Feel free to visit us today at our online store:

LittleDiode.com

Looking forward to providing you with the best possible service.